NSN 5961-01-373-0511

Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-373-0511 **Inclosure Material:** Plastic **Overall Length:** 0.808 inches **Overall Height:** Between 0.080 inches and 0.100 inches **Overall Width:** Between 0.300 inches and 0.320 inches **Component Name And Quantity:** 4 transistor **Mounting Method: Terminal Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: 100.0 drain to source voltage 3rd transistor **Current Rating Per Characteristic:** 950.00 milliamperes drain current 1st transistor and 4.00 amperes off-state current, peak 1st transistor **Power Rating Per Characteristic:** 1.4 milliwatts total power dissipation all transistor **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Terminal Type And Quantity:** 12 tab, solder lug Shelf Life: N/a **Unit Of Measure:** Demilitarization: No Fiig: A110a0